RENESAS

DATASHEET

ISL28286, ISL28486

Dual and Quad Micropower Single Supply Rail-to-Rail Input and Output (RRIO) Precision Op Amp

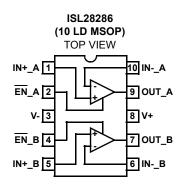
FN6312 Rev 1.00 June 28, 2007

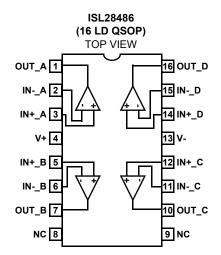
The ISL28286 and ISL28486 are dual and quad channel micropower operational amplifiers optimized for single supply operation over the 2.4V to 5V range. They can be operated from one lithium cell or two Ni-Cd batteries. For equivalent performance in a single channel op amp reference EL8186.

These devices feature an Input Range Enhancement Circuit (IREC) which enables them to maintain CMRR performance for input voltages 10% above the positive supply rail and down to the negative supply. The output operation is rail to rail.

The ISL28286 and ISL28486 draw minimal supply current while meeting excellent DC-accuracy, AC-performance, noise and output drive specifications. The ISL28286 contains a power down enable pin that reduces the power supply current to less than 4μ A max in the disabled state.

Pinouts





Features

- Low power 120µA typical supply current (ISL28286)
- 600µV maximum offset voltage
- 500pA typical input bias current
- 400kHz typical gain-bandwidth product
- 115dB typical PSRR and CMRR
- Single supply operation down to 2.4V
- Input is capable of swinging above V+ and to V- (ground sensing)
- · Rail-to-rail input and output (RRIO)
- · Pb-free plus anneal available (RoHS compliant)

Applications

- Battery- or solar-powered systems
- 4mA to 25mA current loops
- · Handheld consumer products
- Medical devices
- Thermocouple amplifiers
- Photodiode pre-amps
- pH probe amplifiers

Ordering Information

PART NUMBER (Note)			PKG. DWG. #	
ISL28286FUZ*	8286Z	10 Ld MSOP	MDP0043	
ISL28486FAZ*	28486 FAZ	16 Ld QSOP	MDP0040	

*Add "-T7" suffix for tape and reel. Please refer to TB347 for details on reel specifications.

NOTE: Intersil Pb-free plus anneal products employ special Pb-free material sets; molding compounds/die attach materials and 100% matte tin plate termination finish, which are RoHS compliant and compatible with both SnPb and Pb-free soldering operations. Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.



Absolute Maximum Ratings (T_A = +25°C)

Supply Voltage
Supply Turn On Voltage Slew Rate 1V/µs
Differential Input Current 5mA
Differential Input Voltage 0.5V
Input Voltage V 0.5V to V+ + 0.5V
Output Short-Circuit Duration Indefinite
ESD Rating
Human Body Model3kV
Machine Model

Thermal Information

Thermal Resistance	θ _{JA} (°C/W)
10 Ld MSOP Package	115
16 Ld QSOP Package	112
Output Short-Circuit Duration	
Ambient Operating Temperature Range40°	°C to +125°C
Storage Temperature Range65°	°C to +150°C
Operating Junction Temperature	+125°C
Pb-free reflow profiles	ee link below
http://www.intersil.com/pbfree/Pb-FreeReflow.asp	

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

IMPORTANT NOTE: All parameters having Min/Max specifications are guaranteed. Typical values are for information purposes only. Unless otherwise noted, all tests are at the specified temperature and are pulsed tests, therefore: $T_J = T_C = T_A$

Electrical Specifications V₊ = 5V, V₋ = 0V,V_{CM} = 2.5V, R_L = Open, T_A = +25°C unless otherwise specified. Boldface limits apply over the operating temperature range, -40°C to +125°C. Temperature data established by characterization.

PARAMETER	DESCRIPTION	CONDITIONS	MIN (Note 1)	ТҮР	MAX (Note 1)	UNIT
DC SPECIFICATI	ONS					
V _{OS}	Input Offset Voltage		-600 -650	±20	600 650	μV
$\frac{\Delta V_{OS}}{\Delta T}$	Input Offset Voltage vs Temperature			0.7		µV/°C
I _{OS}	Input Offset Current		-2.5 -2.5	±0.25	2.5 2.5	nA
IB	Input Bias Current		-2 -2.5	±0.5	2 2.5	nA
CMIR	Common-Mode Voltage Range	Guaranteed by CMRR	0		5	V
CMRR	Common-Mode Rejection Ratio	V _{CM} = 0V to 5V	90 80	115		dB
PSRR	Power Supply Rejection Ratio	V ₊ = 2.4V to 5V	90 80	115		dB
A _{VOL}	Large Signal Voltage Gain	V_{O} = 0.5V to 4.5V, R _L = 100k Ω	275 275	500		V/mV
		V_{O} = 0.5V to 4.5V, R _L = 1k Ω		95		V/mV
V _{OUT}	Maximum Output Voltage Swing	Output low, $R_L = 100 k\Omega$		3	6 30	mV
		Output low, $R_L = 1k\Omega$		130	175 225	mV
		Output high, $R_L = 100 k\Omega$	4.990 4.970	4.996		V
		Output high, $R_L = 1k\Omega$	4.800 4.750	4.880		V
I _{S,ON}	Supply Current, Enabled	ISL28286, All channels enabled.		120	156 175	μA
		ISL28486, All channels enabled.		240	315 350	μA
I _{S,OFF}	Supply Current, Disabled	ISL28286, All channels disabled.		4	7 9	μA



Electrical Specifications V₊ = 5V, V₋ = 0V,V_{CM} = 2.5V, R_L = Open, T_A = +25°C unless otherwise specified. Boldface limits apply over the operating temperature range, -40°C to +125°C. Temperature data established by characterization. (Continued)

PARAMETER	DESCRIPTION	CONDITIONS	MIN (Note 1)	ТҮР	MAX (Note 1)	UNIT
I _{SC} +	Short Circuit Sourcing Capability	R _L = 10Ω	29 23	31		mA
I _{SC} -	Short Circuit Sinking Capability	R _L = 10Ω	24 19	26		mA
V _{SUPPLY}	Supply Operating Range	V ₊ to V ₋	2.4		5	V
VENH	EN Pin High Level (ISL28286)		2			V
VENL	EN Pin Low Level (ISL28286				0.8	V
IENH	EN Pin Input High Current (ISL28286)	$V_{\overline{EN}} = V_+$		0.7	1.3 1.5	μA
IENL	EN Pin Input Low Current (ISL28286)	$V_{\overline{EN}} = V_{-}$		0	0.1	μA
AC SPECIFICATO	NS					r
GBW	Gain Bandwidth Product	A_V = 100, R _F = 100kΩ, R _G = 1kΩ, R _L = 10kΩ to V _{CM}		400		kHz
e _n	Input Noise Voltage Peak-to-Peak	f = 0.1Hz to 10Hz		4.5		μV _{P-P}
	Input Noise Voltage Density	f _O = 1kHz		50		nVI√Hz
i _n	Input Noise Current Density	f _O = 1kHz		0.18		pA/√Hz
CMRR @ 60Hz	Input Common Mode Rejection Ratio	V_{CM} = 1 V_{P-P} , R_L = 10k Ω to V_{CM}		78		dB
PSRR+ @ 120Hz	Power Supply Rejection Ratio (V+)	$V_+, V = \pm 12V$ and $\pm 2.5V$, $V_{SOURCE} = 1V_{P-P}, R_L = 10k\Omega$ to V_{CM}		-105		dB
PSRR- @ 120Hz	Power Supply Rejection Ratio (V_)	$V_+, V = \pm 12V$ and $\pm 2.5V$ $V_{SOURCE} = 1V_{P-P}, R_L = 10k\Omega$ to V_{CM}		-73		dB
TRANSIENT RES	PONSE	-				
SR	Slew Rate		±0.10 ± 0.09	±0.17	±0.20 ± 0.25	V/µs
t _{EN}	Enable to Output Turn-on Delay Time, 10% EN to 10% V _{OUT} , (ISL28286)	$V_{\overline{EN}}$ = 5V to 0V, A _V = -1, R _g = R _f = R _L = 1k to V _{CM}		2		μs
	Enable to Output Turn-off Delay Time, 10% EN to 10% V _{OUT} , (ISL28286)	$V_{\overline{EN}}$ = 0V to 5V, A _V = -1, R _g = R _f = R _L = 1k to V _{CM}		0.1		μs

NOTE:

1. Parts are 100% tested at +25°C. Over temperature limits established by characterization and are not production tested.

120

80

40

0

-40

-80

1

GAIN (dB

Typical Performance Curves V₊ = 5V, V₋ = 0V,V_{CM} = 2.5V, R_L = Open

80

40

n

40

·80

-120

10M

PHASE (°

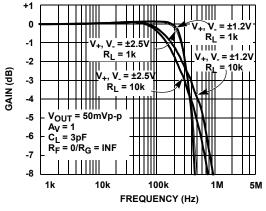


FIGURE 1. FREQUENCY RESPONSE vs SUPPLY VOLTAGE

PHASE

1k

FREQUENCY (Hz)

FIGURE 3. AVOL vs FREQUENCY @ 100k LOAD

GAIN

10k

100k

1M

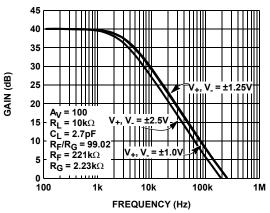


FIGURE 2. FREQUENCY RESPONSE vs SUPPLY VOLTAGE

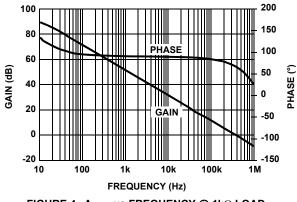
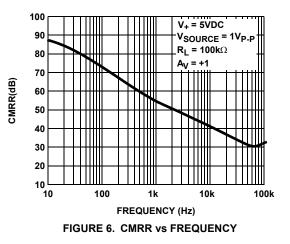
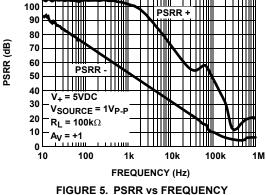


FIGURE 4. AVOL VS FREQUENCY @ 1kΩ LOAD

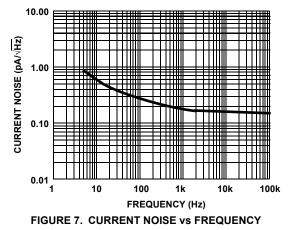


10

100



Typical Performance Curves $V_{+} = 5V$, $V_{-} = 0V$, $V_{CM} = 2.5V$, $R_{L} = Open$ (Continued)



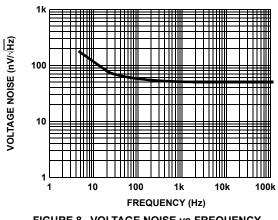
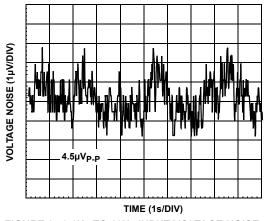
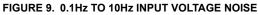


FIGURE 8. VOLTAGE NOISE vs FREQUENCY





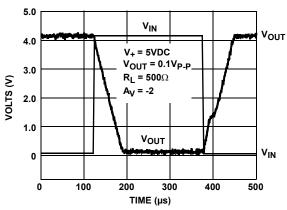
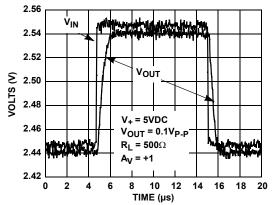


FIGURE 11. LARGE SIGNAL TRANSIENT RESPONSE





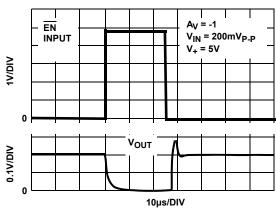


FIGURE 12. ENABLE TO OUTPUT DELAY TIME

Typical Performance Curves $V_{+} = 5V$, $V_{-} = 0V$, $V_{CM} = 2.5V$, $R_{L} = Open$ (Continued)

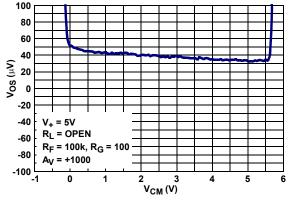


FIGURE 13. INPUT OFFSET VOLTAGE vs COMMON-MODE INPUT VOLTAGE

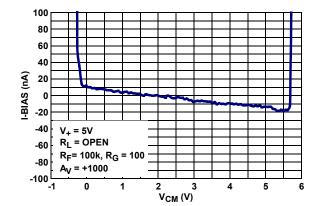


FIGURE 14. INPUT OFFSET CURRENT vs COMMON-MODE INPUT VOLTAGE

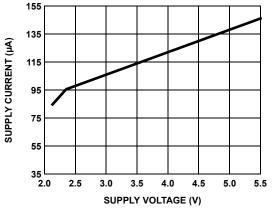
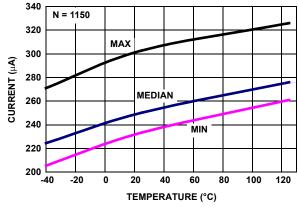
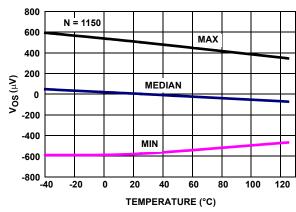


FIGURE 15. ISL28286 SUPPLY CURRENT vs SUPPLY VOLTAGE

ΜΑΧ









40

TEMPERATURE (°C)

4.8

4.6

4.4

4.2

4.0

3.8

3.6

3.4

3.2

-40

-20

0

20

CURRENT (µA)

N = 12



MEDIAN

120

100

MIN

80

60

Typical Performance Curves V₊ = 5V, V₋ = 0V, V_{CM} = 2.5V, R_L = Open (Continued)

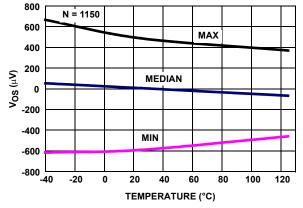


FIGURE 19. V_{OS} vs TEMPERATURE, V_{IN} = 0V, V_+ , V_- = ±1.2V

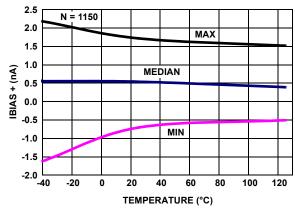


FIGURE 20. IBIAS + vs TEMPERATURE, V₊, V₋ = ±2.5V

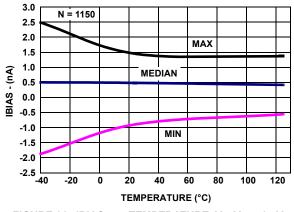


FIGURE 21. IBIAS - vs TEMPERATURE, V₊, V₋ = ±2.5V

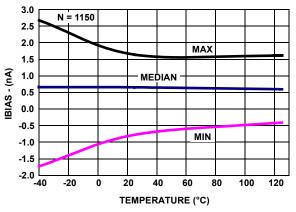


FIGURE 23. IBIAS - vs TEMPERATURE, V+, V_ = ±1.2V

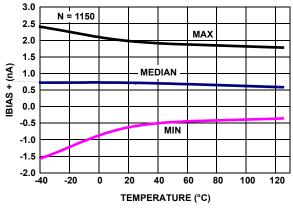
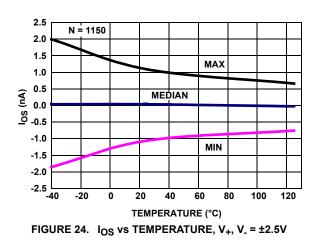


FIGURE 22. IBIAS + vs TEMPERATURE, V+, V_ = ±1.2V



Typical Performance Curves V₊ = 5V, V₋ = 0V, V_{CM} = 2.5V, R_L = Open (Continued)

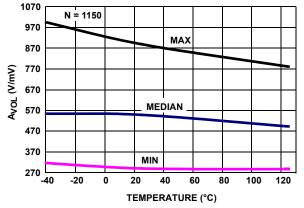


FIGURE 25. A_{VOL} vs TEMPERATURE, V₊, V₋ = ±2.5V, R_L = 100k

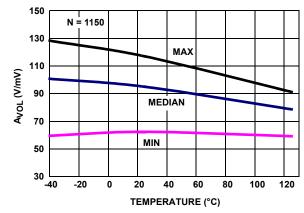


FIGURE 26. A_{VOL} vs TEMPERATURE, V₊, V₋ = ±2.5V, R_L = 1k

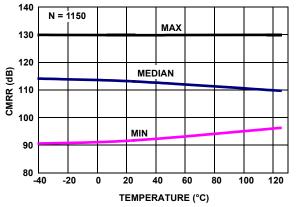


FIGURE 27. CMRR vs TEMPERATURE, V_{CM} = +2.5V TO -2.5V, $V_{+}, V_{-} = \pm 2.5V$

N = 1150

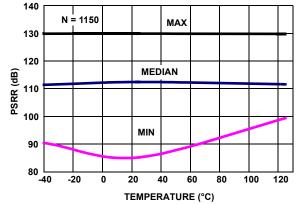


FIGURE 28. PSRR vs TEMPERATURE, V+, V_ = ±1.2V TO ±2.75V

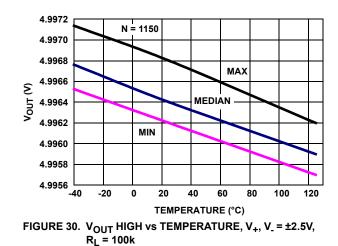


FIGURE 29. V_{OUT} HIGH vs TEMPERATURE, V_+ , V_- = ±2.5V,

TEMPERATURE (°C)

40

MAX

MIN

MEDIAN

60

80

100

120



4.91

4.90

4.89

4.88

4.87

4.86

4.85 └─ -40

-20

 $R_L = 1k$

0

20

Vout (V)

Typical Performance Curves $V_{+} = 5V$, $V_{-} = 0V$, $V_{CM} = 2.5V$, $R_{L} = Open$ (Continued)

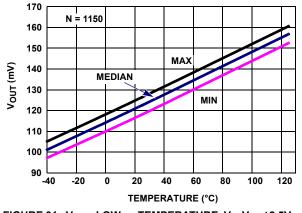


FIGURE 31. V_{OUT} LOW vs TEMPERATURE, V₊, V₋ = ±2.5V, R_L = 1k

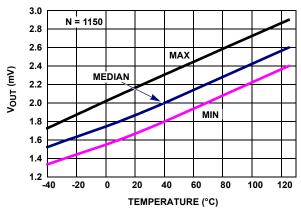
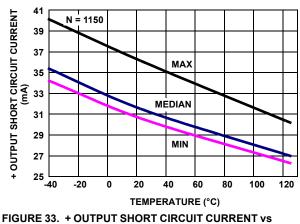
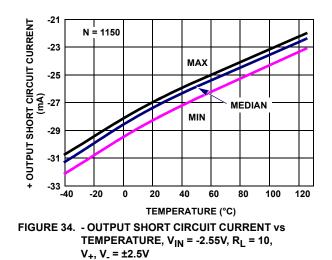
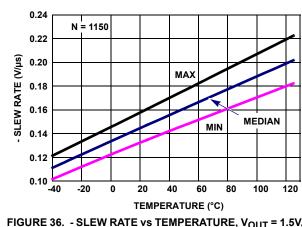


FIGURE 32. V_{OUT} LOW vs TEMPERATURE, V₊, V₋ = $\pm 2.5V$, R_L = 100k

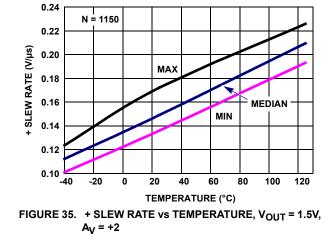


TEMPERATURE, $V_{IN} = -2.55V$, $R_L = 10$, V_+ , $V_- = \pm 2.5V$







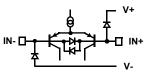


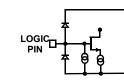
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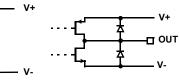


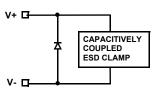
Pin Descriptions

ISL28286 (10 LD MSOP)	ISL28486 (16 LD QSOP)	PIN NAME	EQUIVALENT CIRCUIT	DESCRIPTION
1	3	IN+_A	Circuit 1	Amplifier A non-inverting input
2		EN_A	Circuit 2	Amplifier A enable pin internal pull-down; Logic "1" selects the disabled state; Logic "0" selects the enabled state.
3	13	V-	Circuit 4	Negative power supply
4		EN_B	Circuit 2	Amplifier B enable pin with internal pull-down; Logic "1" selects the disabled state; Logic "0" selects the enabled state.
5	5	IN+_B	Circuit 1	Amplifier B non-inverting input
6	6	INB	Circuit 1	Amplifier B inverting input
7	7	OUT_B	Circuit 3	Amplifier B output
8	4	V+	Circuit 4	Positive power supply
9	1	OUT_A	Circuit 3	Amplifier A output
10	2	INA	Circuit 1	Amplifier A inverting input
	10	OUT_C	Circuit 3	Amplifier C output
	11	INC	Circuit 1	Amplifier C inverting input
	12	IN+_C	Circuit 1	Amplifier C non-inverting input
	14	IN+_D	Circuit 1	Amplifier D non-inverting input
	15	IND	Circuit 1	Amplifier D inverting input
	16	OUT_D	Circuit 3	Amplifier D output
	8, 9	NC	-	No internal connection









CIRCUIT 1

CIRCUIT 2

CIRCUIT 3

CIRCUIT 4

Applications Information

Introduction

The ISL28286 and ISL28486 are dual and quad BiCMOS railto-rail input, output (RRIO) micropower precision operational amplifiers. These devices are designed to operate from a single supply (2.4V to 5.0V) or dual supplies (\pm 1.2V to \pm 2.5V) while drawing only 120µA (ISL28286) of supply current. This combination of low power and precision performance makes these devices suitable for solar and battery power applications.

Rail-to-Rail Input

Many rail-to-rail input stages use two differential input pairs, a long-tail PNP (or PFET) and an NPN (or NFET). Severe penalties have to be paid for this circuit topology. As the input signal moves from one supply rail to another, the operational amplifier switches from one input pair to the other causing drastic changes in input offset voltage and an undesired change in magnitude and polarity of input offset current.

The ISL28286 and ISL28486 achieve input rail-to-rail without sacrificing important precision specifications and degrading distortion performance. The devices' input offset voltage exhibits a smooth behavior throughout the entire common-mode input range. The input bias current versus the common-mode voltage range gives us an undistorted behavior from typically down to the negative rail to 10% higher than the V+ rail (0.5V higher than V+ when V+ equals 5V).

Input Protection

All input terminals have internal ESD protection diodes to positive and negative supply rails, limiting the input voltage to within one diode beyond the supply rails. Both parts have additional back-to-back diodes across the input terminals. If overdriving the inputs is necessary, the external input current must never exceed 5mA. External series resistors may be used as an external protection to limit excessive external voltage and current from damaging the inputs.

Input Bias Current Compensation

The ISL28286 and ISL28486 contain an input bias cancellation circuit which reduces the bias currents down to a typical of 500pA while maintaining an excellent bandwidth for a micropower operational amplifier. The input stage transistors are still biased with adequate current for speed but the canceling circuit sinks most of the base current, leaving a small fraction as input bias current.

Rail-to-Rail Output

A pair of complementary MOSFET devices are used to achieve the rail-to-rail output swing. The NMOS sinks current to swing the output in the negative direction. The PMOS sources current to swing the output in the positive direction. Both parts with a 100k Ω load will swing to within 4mV of the supply rails.

Enable/Disable Feature

The ISL28286 offers two \overline{EN} pins (\overline{EN} _A and \overline{EN} _B) which disable the op amp when pulled up to at least 2.0V. In the

disabled state (output in a high impedance state), the part consumes typically 4µA. By disabling the part, multiple parts can be connected together as a MUX. The outputs are tied together in parallel and a channel can be selected by the EN pins. The EN pins also have an internal pull-down. If left open, the EN pins will pull to the negative rail and the op amp will be enabled by default.

Using Only One Channel

The ISL28286 and ISL28486 are dual and quad channel op amps. If the application only requires one channel when using the ISL28286 or less than 4 channels when using the ISL28486, the user must configure the unused channel(s) to prevent them from oscillating. The unused channel(s) will oscillate if the input and output pins are floating. This will result in higher than expected supply currents and possible noise injection into the channel being used. The proper way to prevent this oscillation is to short the output to the negative input and ground the positive input (as shown in Figure 37).

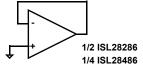


FIGURE 37. PREVENTING OSCILLATIONS IN UNUSED CHANNELS

Proper Layout Maximizes Performance

To achieve the maximum performance of the high input impedance and low offset voltage of the ISL28286 and ISL28486, care should be taken in the circuit board layout. The PC board surface must remain clean and free of moisture to avoid leakage currents between adjacent traces. Surface coating of the circuit board will reduce surface moisture and provide a humidity barrier, reducing parasitic resistance on the board. When input leakage current is a concern, the use of guard rings around the amplifier inputs will further reduce leakage currents. Figure 38 shows a guard ring example for a unity gain amplifier that uses the low impedance amplifier output at the same voltage as the high impedance input to eliminate surface leakage. The guard ring does not need to be a specific width, but it should form a continuous loop around both inputs. For further reduction of leakage currents, components can be mounted to the PC board using Teflon standoff insulators.

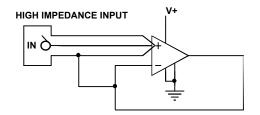


FIGURE 38. GUARD RING EXAMPLE FOR UNITY GAIN AMPLIFIER



Current Limiting

The ISL28286 and ISL28486 have no internal current-limiting circuitry. If the output is shorted, it is possible to exceed the Absolute Maximum Rating for output current or power dissipation, potentially resulting in the destruction of the device.

Power Dissipation

It is possible to exceed the +150°C maximum junction temperatures under certain load and power-supply conditions. It is therefore important to calculate the maximum junction temperature (T_{JMAX}) for all applications to determine if power supply voltages, load conditions, or package type need to be modified to remain in the safe operating area. These parameters are related as follows:

$$T_{JMAX} = T_{MAX} + (\theta_{JA} x PD_{MAXTOTAL})$$
(EQ. 1)

where:

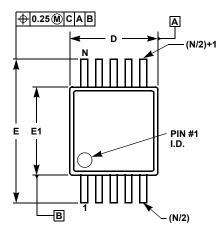
- P_{DMAXTOTAL} is the sum of the maximum power dissipation of each amplifier in the package (PD_{MAX})
- PD_{MAX} for each amplifier can be calculated as follows:

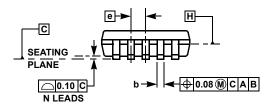
$$PD_{MAX} = 2*V_{S} \times I_{SMAX} + (V_{S} - V_{OUTMAX}) \times \frac{V_{OUTMAX}}{R_{L}} (EQ. 2)$$

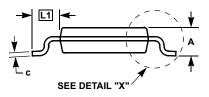
where:

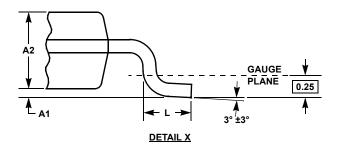
- T_{MAX} = Maximum ambient temperature
- θ_{JA} = Thermal resistance of the package
- PD_{MAX} = Maximum power dissipation of 1 amplifier
- V_S = Supply voltage (Magnitude of V₊ and V₋)
- I_{MAX} = Maximum supply current of 1 amplifier
- V_{OUTMAX} = Maximum output voltage swing of the application
- R_L = Load resistance

Mini SO Package Family (MSOP)









MDP0043

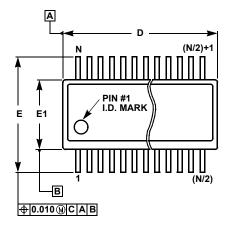
MINI SO PACKAGE FAMILY

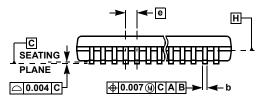
	MILLIMETERS			
SYMBOL	MSOP8	MSOP10	TOLERANCE	NOTES
А	1.10	1.10	Max.	-
A1	0.10	0.10	±0.05	-
A2	0.86	0.86	±0.09	-
b	0.33	0.23	+0.07/-0.08	-
С	0.18	0.18	±0.05	-
D	3.00	3.00	±0.10	1, 3
E	4.90	4.90	±0.15	-
E1	3.00	3.00	±0.10	2, 3
е	0.65	0.50	Basic	-
L	0.55	0.55	±0.15	-
L1	0.95	0.95	Basic	-
Ν	8	10	Reference	-
	·			Rev. D 2/07

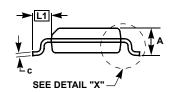
NOTES:

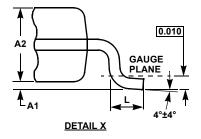
- 1. Plastic or metal protrusions of 0.15mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25mm maximum per side are not included.
- 3. Dimensions "D" and "E1" are measured at Datum Plane "H".
- 4. Dimensioning and tolerancing per ASME Y14.5M-1994.

Quarter Size Outline Plastic Packages Family (QSOP)









MDP0040

QUARTER SIZE OUTLINE PLASTIC PACKAGES FAMILY

	INCHES					
SYMBOL	QSOP16	QSOP24	QSOP28	TOLERANCE	NOTES	
A	0.068	0.068	0.068	Max.	-	
A1	0.006	0.006	0.006	±0.002	-	
A2	0.056	0.056	0.056	±0.004	-	
b	0.010	0.010	0.010	±0.002	-	
с	0.008	0.008	0.008	±0.001	-	
D	0.193	0.341	0.390	±0.004	1, 3	
E	0.236	0.236	0.236	±0.008	-	
E1	0.154	0.154	0.154	±0.004	2, 3	
е	0.025	0.025	0.025	Basic	-	
L	0.025	0.025	0.025	±0.009	-	
L1	0.041	0.041	0.041	Basic	-	
N	16	24	28	Reference	-	
Rev. F 2/07						

NOTES:

1. Plastic or metal protrusions of 0.006" maximum per side are not included.

2. Plastic interlead protrusions of 0.010" maximum per side are not included.

3. Dimensions "D" and "E1" are measured at Datum Plane "H".

4. Dimensioning and tolerancing per ASME Y14.5M-1994.

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